Hi-Rel GaAs MESFET from MwT

3/30/2022 – San Jose, California: RFMW announces availability of discrete devices from Microwave Technology (MwT). The MwT-9F70 GaAs MESFET delivers 26.5 dBm P1dB at 12 GHz and is ideally suited to applications requiring high-gain and medium linear power in the 500 MHz to 26 GHz frequency range. Small signal gain is 11 dB. Offered in a -70 ceramic package, the MwT-9F70 can be used in military and hi-rel SWaP designs and is also available in DIE and other packaged configurations, all with MTBF values better than 1x108 hours at 150 degrees C channel temperature.

Samples are available for qualified requirements through RFMW at 1-877-FOR RFMW (367-7369) within North America; or please find your local sales engineer (worldwide) at the contact page on the RFMW web site.

About RFMW

RFMW is a specialty electronics distribution company focused exclusively on serving customers that require RF and microwave components and semiconductors, as well as component engineering support. The company continues to expand its list of products from selective suppliers with RF/microwave expertise. RFMW deploys a highly experienced, technically skilled team to assist customers with component selection and fulfillment.

To learn more about RFMW, visit their Website at www.rfmw.com, or call us at 1.877.FOR.RFMW (367-7369), or via e-mail at info@rfmw.com.

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